3.5x2.8 mm SMD CHIP LED LAMP

Part Number: KA-3529SYS-L1

PRELIMINARY SPEC

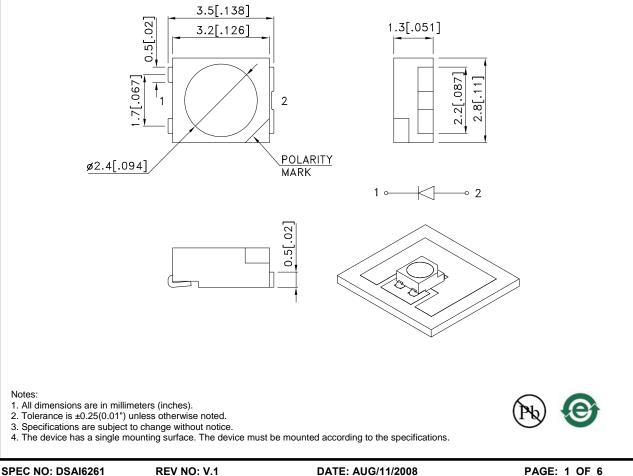
Features

- •SINGLE COLOR.
- •SUITABLE FOR ALL SMT ASSEMBLY AND SOLDER PROCESS.
- •AVAILABLE ON TAPE AND REEL.
- ●IDEAL FOR BACKLIGHTING.
- **•**WHITE SMD PACKAGE, SILICONE RESIN.
- •LOW THERMAL RESISTANCE.
- •PACKAGE: 1500PCS / REEL.
- •MOISTURE SENSITIVITY LEVEL : LEVEL 2a.
- •RoHS COMPLIANT.

Description

The source color devices are made with AlInGaP Light Emitting Diode.

Package Dimensions

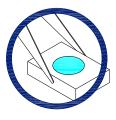


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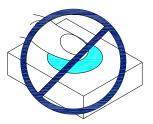
Handling Precautions

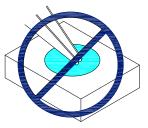
Compare to epoxy encapsulant that is hard and brittle, silicone is softer and flexible. Although its characteristic significantly reduces thermal stress, it is more susceptible to damage by external mechanical force. As a result, special handling precautions need to be observed during assembly using silicone encapsulated LED products. Failure to comply might leads to damage and premature failure of the LED.

1. Handle the component along the side surfaces by using forceps or appropriate tools.



2. Do not directly touch or handle the silicone lens surface. It may damage the internal circuitry.

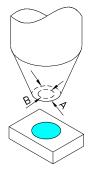




3. Do not stack together assembled PCBs containing exposed LEDs. Impact may scratch the silicone lens or damage the internal circuitry.



4. The outer diameter of the SMD pickup nozzle should not exceed the size of the LED to prevent air leaks. The inner diameter of the nozzle should be as large as possible.
5. A pliable material is suggested for the nozzle tip to avoid scratching or damaging the LED surface during pickup.
6. The dimensions of the component must be accurately programmed in the pick-and-place machine to insure precise pickup and avoid damage during production.



Selection Guide										
Part No.	Dice	Lens Type	lv (mcd) [2] @ 150mA		Φν (mlm) [2] @ 150mA		Viewing Angle [1]			
			Min.	Тур.	Min.	Тур.	201/2			
KA-3529SYS-L1	Super Bright Yellow (AlInGaP)	WATER CLEAR	1600	3000	3000	6000	120°			

Notes:

01/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
 Luminous intensity / luminous flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Parameter	Symbol	Value	Unit
Power Dissipation	Pt	615	mW
Junction Temperature [1]	TJ	110	°C
Operating Temperature	Тор	-40 To +85	°C
Storage Temperature	Tstg	-40 To +85	°C
DC Forward Current [1]	lF	150	mA
Peak Forward Current [2]	IFM	200	mA
Thermal Resistance [1] (Junction/ambient)	Rth j-a	210	°C/W
Thermal Resistance [1] (Junction/solder point)	Rth j-S	90	°C/W

Notes:

1.Results from mounting on PC board FR4(pad size≥70mm²), mounted on pc board-metal core PCB is recommend

for lowest thermal Resistance. 2.1/10 Duty Cycle, 0.1ms Pulse Width.

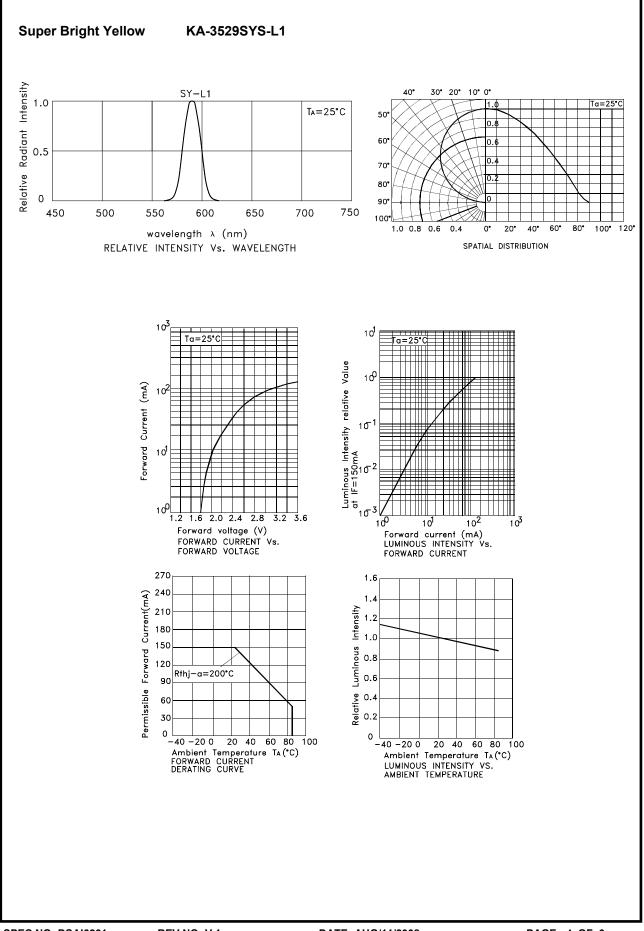
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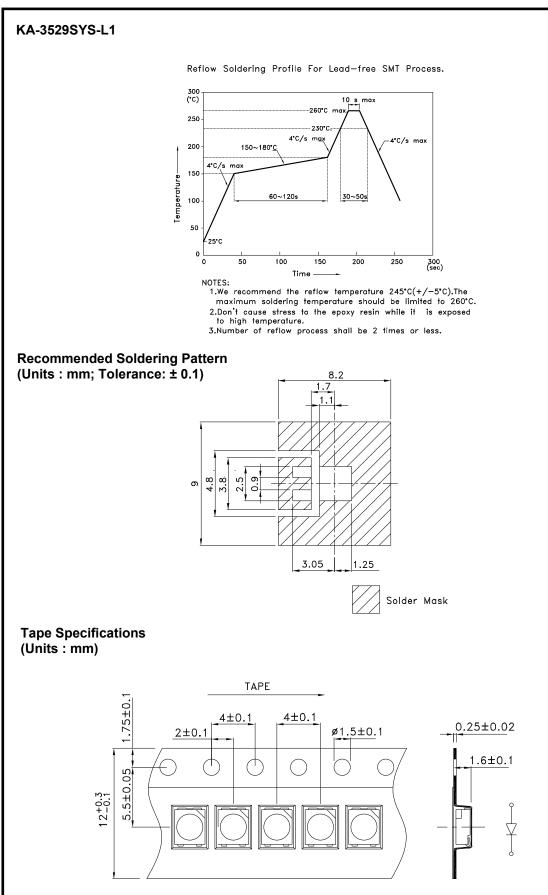
Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Yellow	590		nm	IF=150mA
λD [1]	Dominant Wavelength	Super Bright Yellow	590		nm	IF=150mA
Δλ1/2	Spectral Line Half-width	Super Bright Yellow	20		nm	IF=150mA
С	Capacitance	Super Bright Yellow	20		pF	VF=0V;f=1MHz
Vf [2]	Forward Voltage	Super Bright Yellow	3.6	4.1	V	IF=150mA
IR	Reverse Current	Super Bright Yellow		10	uA	Vr = 5V

Notes:

1.Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.





DATE: AUG/11/2008 DRAWN: R.CHEN

